

Features

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected**
- **Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **The DMG1013UWQ is suitable for automotive applications requiring specific change control; this part is AEC-Q101 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.**

<https://www.diodes.com/quality/product-definitions/>

Mechanical Data

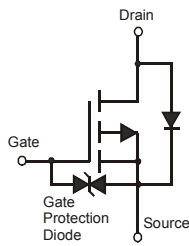
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound.
UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram Below
- Terminals: Finish - Matte Tin Annealed over Alloy 42 Leadframe.
Solderable per MIL-STD-202, Method 208 **Ⓔ3**
- Weight: 0.006 grams (Approximate)



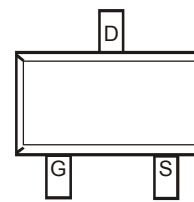
ESD PROTECTED



Top View



Pinout Circuit



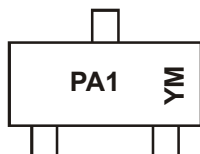
Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
DMG1013UWQ-7	SOT323	3000 / Tape & Reel
DMG1013UWQ-13	SOT323	10000 / Tape & Reel

- Notes:
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
 2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



PA1 = Product Type Marking Code
 YM or YM = Date Code Marking
 Y or Y = Year (ex: I = 2021)
 M = Month (ex: 9 = September)

Date Code Key

Year	2008		2021	2022	2023	2024	2025	2026	2027	2028	2029	2030
Code	V		I	J	K	L	M	N	O	P	R	S

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	O	N	D

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-20	V
Gate-Source Voltage			V_{GSS}	± 6	V
Continuous Drain Current (Note 5)	Steady State	$T_A = +25^\circ\text{C}$ $T_A = +85^\circ\text{C}$	I_D	-0.82 -0.54	A
Pulsed Drain Current (Note 6)			I_{DM}	-3	A

Thermal Characteristics

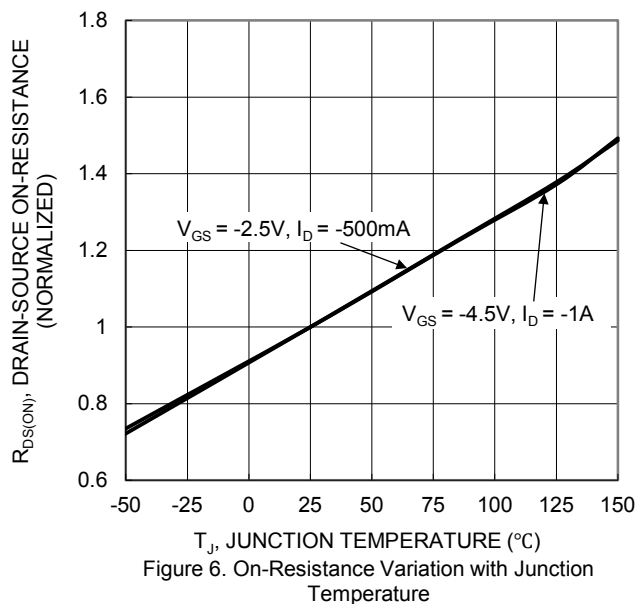
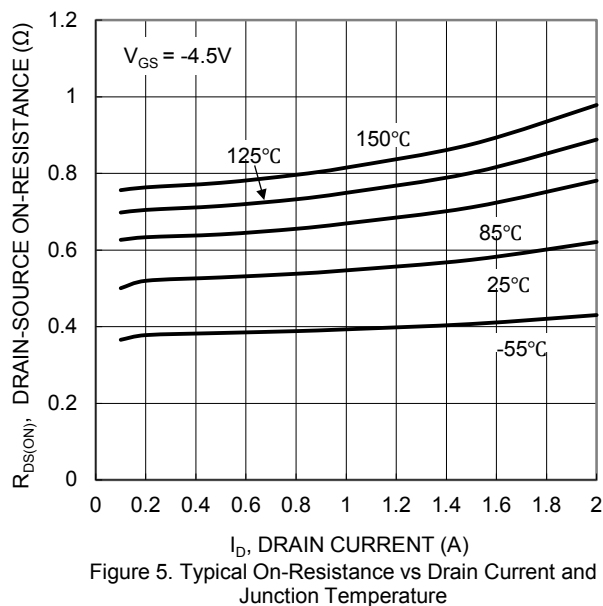
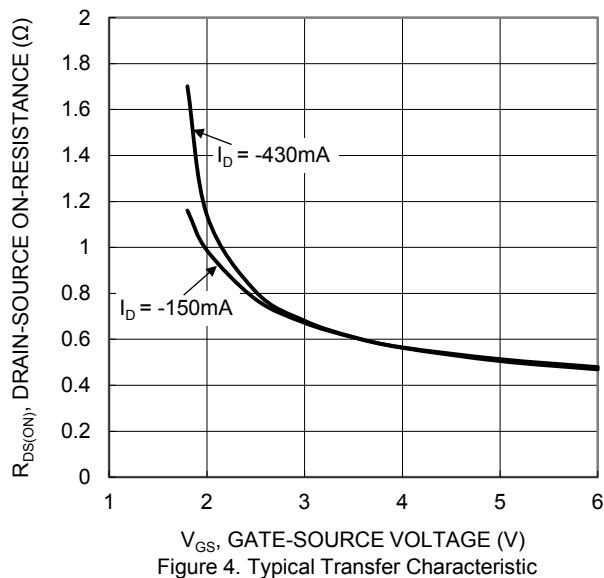
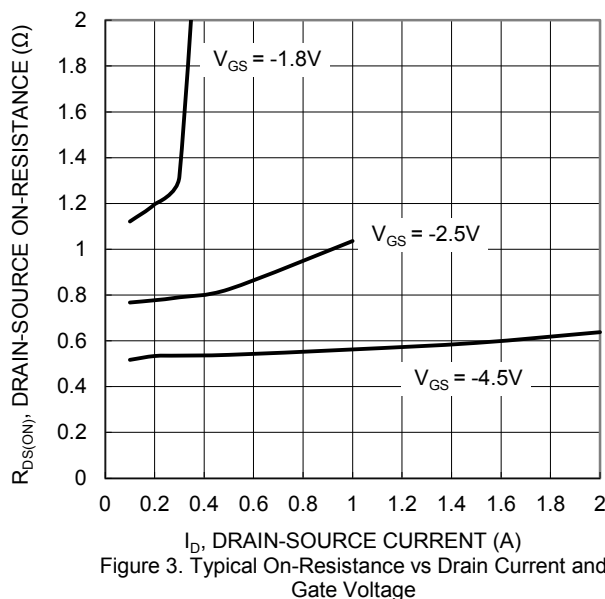
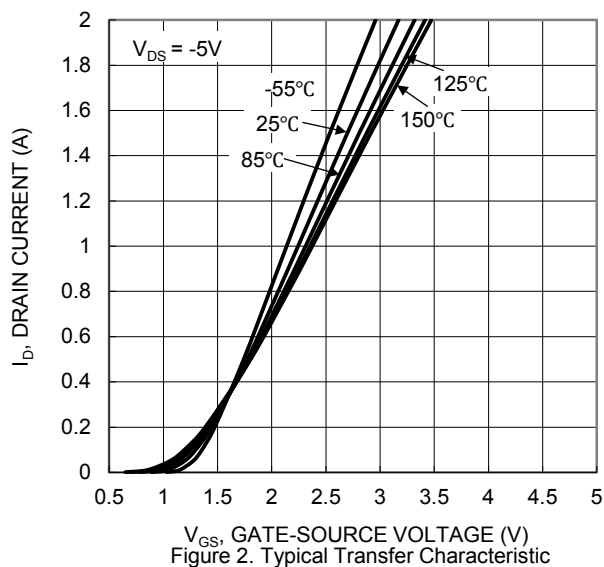
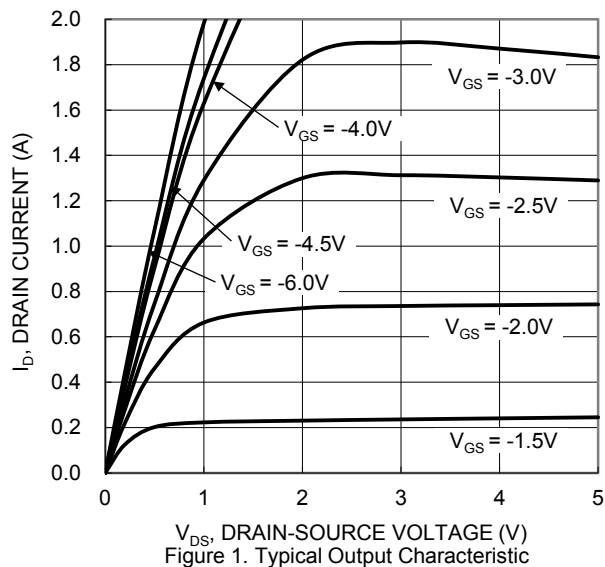
Characteristic		Symbol	Value	Unit
Power Dissipation (Note 5)		P_D	0.31	W
Thermal Resistance, Junction to Ambient	@ $T_A = +25^\circ\text{C}$ (Note 5)	$R_{\theta JA}$	398	$^\circ\text{C/W}$
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

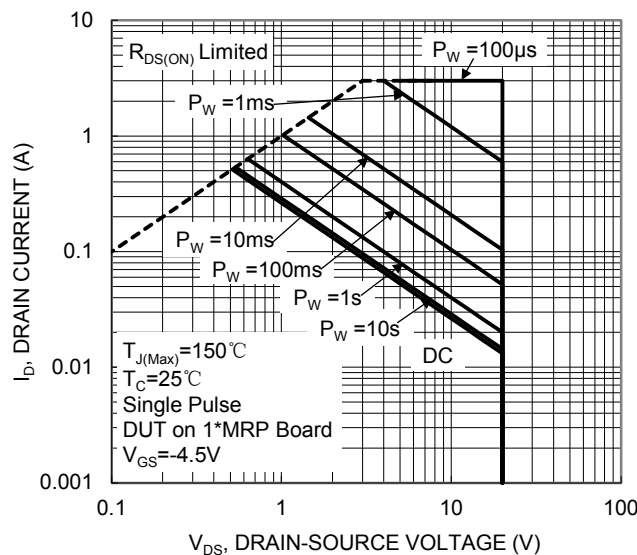
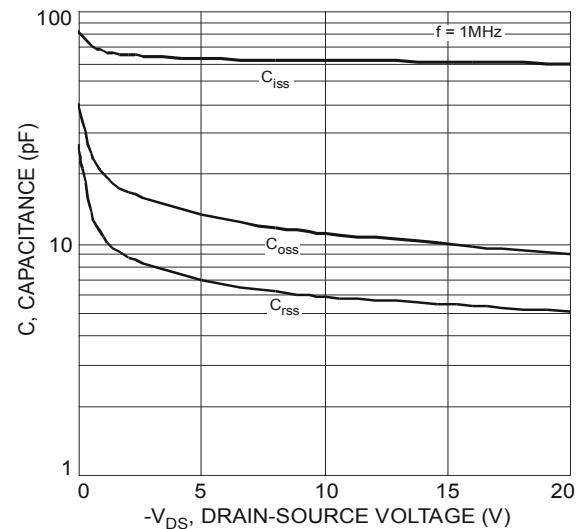
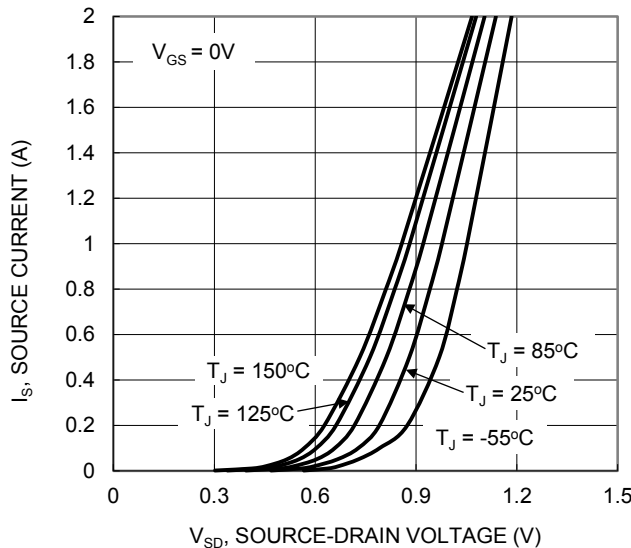
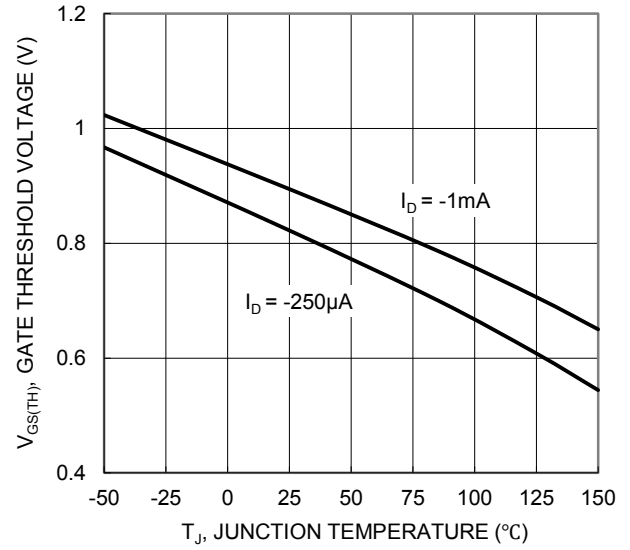
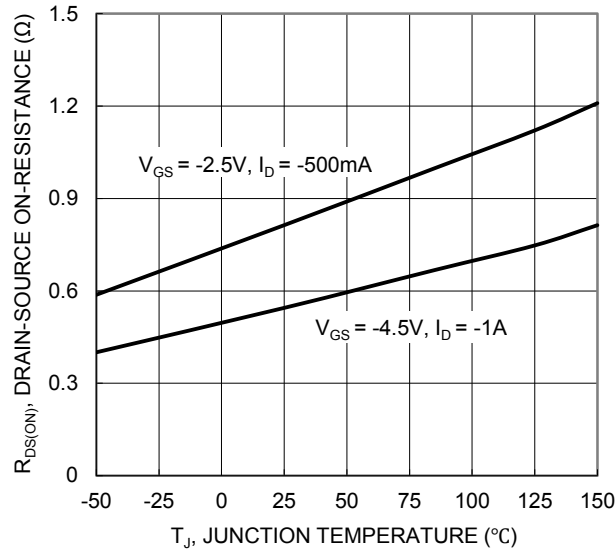
Notes: 5. Device mounted on FR-4 PCB, with minimum recommended pad layout.
6. Repetitive rating, pulse width limited by junction temperature.

Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BV_{DSS}	-20	-	-	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^\circ\text{C}$	I_{DSS}	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$
Gate-Source Leakage	I_{GSS}	-	-	± 2.0	μA	$V_{GS} = \pm 4.5V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	$V_{GS(TH)}$	-0.5	-	-1.0	V	$V_{DS} = V_{GS}, I_D = -250\mu A$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	-	0.5	0.75	Ω	$V_{GS} = -4.5V, I_D = -430mA$
			0.7	1.05		$V_{GS} = -2.5V, I_D = -300mA$
			1.0	1.5		$V_{GS} = -1.8V, I_D = -150mA$
Forward Transfer Admittance	$ Y_{fs} $	-	0.9	-	S	$V_{DS} = -10V, I_D = -250mA$
Diode Forward Voltage	V_{SD}	-	-0.8	-1.2	V	$V_{GS} = 0V, I_S = -150mA$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	C_{iss}	-	59.76	-	pF	$V_{DS} = -16V, V_{GS} = 0V,$ $f = 1.0MHz$
Output Capacitance	C_{oss}	-	12.07	-	pF	
Reverse Transfer Capacitance	C_{rss}	-	6.36	-	pF	
Total Gate Charge	Q_g	-	622.4	-	pC	$V_{GS} = -4.5V, V_{DS} = -10V,$ $I_D = -250mA$
Gate-Source Charge	Q_{gs}	-	100.3	-	pC	
Gate-Drain Charge	Q_{gd}	-	132.2	-	pC	
Turn-On Delay Time	$t_{D(ON)}$	-	5.1	-	ns	$V_{DD} = -10V, V_{GS} = -4.5V,$ $R_L = 47\Omega, R_G = 10\Omega,$ $I_D = -200mA$
Turn-On Rise Time	t_R	-	8.1	-	ns	
Turn-Off Delay Time	$t_{D(OFF)}$	-	28.4	-	ns	
Turn-Off Fall Time	t_F	-	20.7	-	ns	

Notes: 7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.





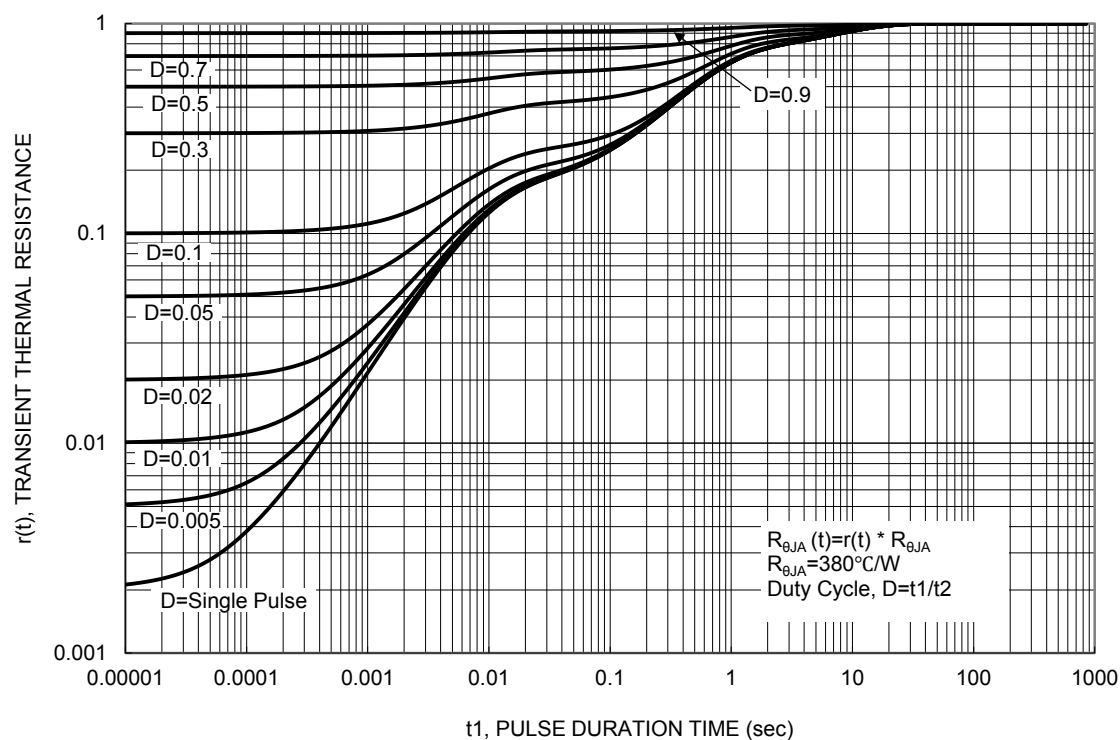
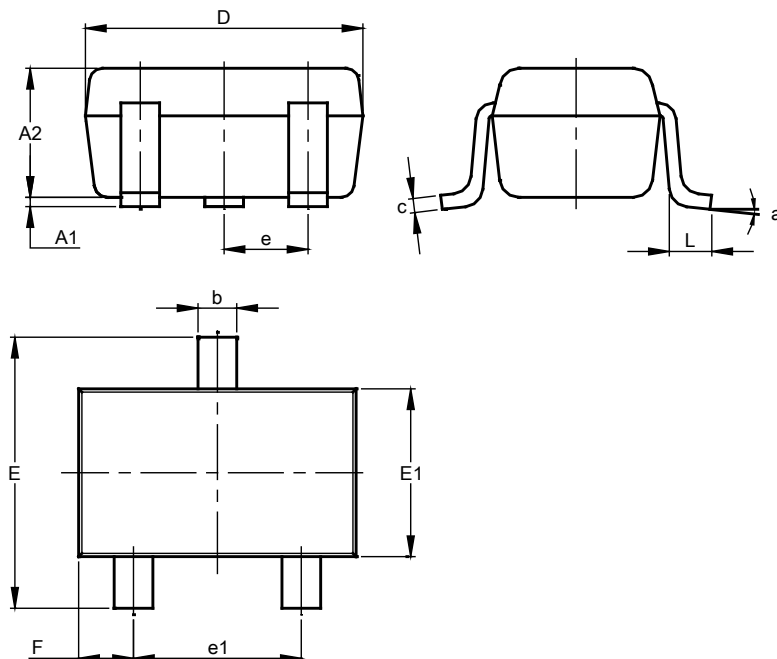


Figure 12. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT323

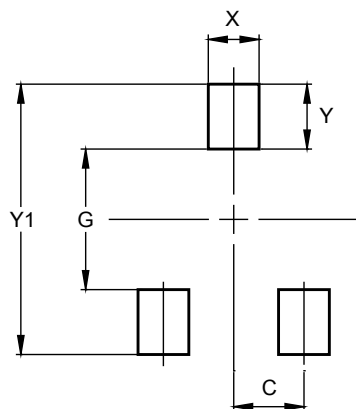


SOT323			
Dim	Min	Max	Typ
A1	0.00	0.10	0.05
A2	0.90	1.00	0.95
b	0.25	0.40	0.30
c	0.10	0.18	0.11
D	1.80	2.20	2.15
E	2.00	2.20	2.10
E1	1.15	1.35	1.30
e	0.650 BSC		
e1	1.20	1.40	1.30
F	0.375	0.475	0.425
L	0.25	0.40	0.30
a	8°		
All Dimensions in mm			

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

SOT323



Dimensions	Value (in mm)
C	0.650
G	1.300
X	0.470
Y	0.600
Y1	2.500

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